

LSF0102-Q1 汽车类 2 通道自动双向多电压电平转换器

1 特性

- 符合面向汽车应用的 AEC-Q100 标准
 - 温度等级 1 : $-40^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$
 - 器件 HBM ESD 分类等级 2
 - CDM ESD 分类等级 C6
- 用无方向引脚提供双向电压转换
- 支持开漏和推挽应用, 如 I²C、SPI、UART、MDIO、SDIO 和 GPIO
- 在不超过 30pF 的容性负载条件下支持最高达 100MHz 的上行转换和超过 100MHz 的下行转换, 在 50pF 的容性负载条件下支持高达 40MHz 的上行/下行转换
- 可实现以下电压之间的双向电压电平转换
 - 0.95V ↔ 1.8/2.5/3.3/5V
 - 1.2V ↔ 1.8/2.5/3.3/5V
 - 1.8V ↔ 2.5/3.3/5V
 - 2.5V ↔ 3.3/5V
 - 3.3V ↔ 5V
- 低待机电流
- 5V 耐受 I/O 端口, 可支持 TTL 电压电平
- 低导通电阻, 可减少信号失真
- EN = 低电平时为高阻抗 I/O 引脚
- 采用直通引脚排列以简化 PCB 布线
- 闩锁性能超过 100mA, 符合 JESD 78 II 类规范的要求

2 应用

- 信息娱乐系统音响主机
- 图形群集
- ADAS 融合
- ADAS 前置摄像头
- HEV 电池管理系统

3 说明

LSF0102-Q1 器件是一款自动双向电压转换器, 无需方向引脚即可在广泛的电源范围内进行转换。当容性负载 $\leq 30\text{pF}$ 时, LSF0102-Q1 支持最高 100MHz 的升压转换和高于 100MHz 的降压转换。此外, 当容性负载为 50pF 时, LSF0102-Q1 支持最高 40MHz 的上行和下行转换, 因此, LSF0102-Q1 器件可支持汽车中各种常见的标准接口, 如 I²C、SPI、GPIO、SDIO、UART 和 MDIO。

LSF0102-Q1 器件具有 5V 耐受数据输入。因此该器件可兼容 TTL 电压电平。此外, LSF0102-Q1 还支持混合模式电压转换, 可在各个通道上升压和降压转换至不同的电源电平。

器件信息⁽¹⁾

| 器件型号 | 封装 (引脚) | 封装尺寸 (标称值) |
|----------------|-----------|-----------------|
| LSF0102QDCURQ1 | VSSOP (8) | 2.30mm x 2.00mm |

- (1) 如需了解所有可用封装, 请参阅数据表末尾的可订购产品附录。

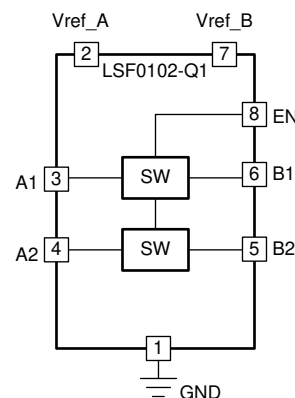


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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

| Changes from Revision * (May 2018) to Revision A (April 2021) | Page |
|--|------|
| • 更新了整个文档中的表格、图和交叉参考的编号格式..... | 1 |
| • Updated the <i>Bidirectional Translation</i> section to include inclusive terminology..... | 11 |

5 Pin Configuration and Functions

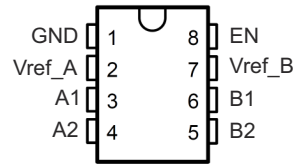


图 5-1. LSF0102-Q1 DCU Package 8-Pin VSSOP Top View

表 5-1. Pin Functions

| PIN | | I/O | DESCRIPTION |
|--------|-----|-----|---|
| NAME | DCU | | |
| A1 | 3 | I/O | Input/Output A port for Channel 1 |
| A2 | 4 | I/O | Input/Output A port for Channel 2 |
| B1 | 6 | I/O | Input/Output B port for Channel 1 |
| B2 | 5 | I/O | Input/Output B port for Channel 2 |
| EN | 8 | I | I/O enable input; see 图 8-1 for typical setup. Should be tied directly to Vref_B to be enabled or pulled LOW to disable all I/O pins. |
| GND | 1 | — | Ground |
| Vref_A | 2 | — | A side reference supply voltage; see 节 8 for setup and supply voltage range. |
| Vref_B | 7 | — | B side reference supply voltage. Must be connected to supply through 200 kΩ; see 节 8 for setup and supply voltage range. |

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature (unless otherwise noted)⁽¹⁾

| | MIN | MAX | UNIT |
|---|-----------|------|------|
| Input voltage ⁽²⁾ , V_I | - 0.5 | 7 | V |
| Input/output voltage ⁽²⁾ , $V_{I/O}$ | - 0.5 | 7 | V |
| Continuous channel current | | 128 | mA |
| Input clamp current, I_{IK} | $V_I < 0$ | - 50 | mA |
| Storage temperature range, T_{stg} | - 65 | 150 | °C |
| Operating junction temperature, T_J | | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and input/output negative-voltage ratings may be exceeded if the input and input/output clamp-current ratings are observed.

6.2 ESD Ratings

| | VALUE | UNIT |
|-------------------------------------|---|-------|
| $V_{(ESD)}$ Electrostatic discharge | Human-body model (HBM), per AEC Q100-002 ⁽¹⁾ | ±2000 |
| | Charged-device model (CDM), per AEC Q100-011 | ±1000 |

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

| | MIN | MAX | UNIT |
|--------------------------------------|------|-----|------|
| $V_{I/O}$ Input/output voltage | | 5 | V |
| $V_{ref_A/B/EN}$ Reference voltage | | 5 | V |
| I_{PASS} Pass transistor current | | 64 | mA |
| T_A Operating free-air temperature | - 40 | 125 | °C |

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | LSF0102-Q1 | UNIT |
|--|------------|------|
| | DCU (US8) | |
| | 8 PINS | |
| $R_{\theta JA}$ Junction-to-ambient thermal resistance | 229.3 | °C/W |
| $R_{\theta JC(top)}$ Junction-to-case (top) thermal resistance | 106.5 | °C/W |
| $R_{\theta JB}$ Junction-to-board thermal resistance | 141.7 | °C/W |
| ψ_{JT} Junction-to-top characterization parameter | 35.3 | °C/W |
| ψ_{JB} Junction-to-board characterization parameter | 141.4 | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | | TEST CONDITIONS | MIN | TYP ⁽¹⁾ | MAX | UNIT |
|--|---|---|---|--------------------|------|---------------|
| V_{IK} | Input clamp voltage | $I_I = -18 \text{ mA}, V_{EN} = 0$ | | -1.2 | | V |
| I_{IH} | I/O input high leakage | $V_I = 5 \text{ V}, V_{EN} = 0$ | | 5.0 | | μA |
| I_{CCBA} | V_{ref_B} to V_{ref_A} leakage | $V_{ref_B} = V_{EN} = 5.5 \text{ V}, V_{ref_A} = 4.5 \text{ V}, I_O = 0, V_I = V_{CC}$ or GND | | 1 | | μA |
| $C_{I(ref_A/B/EN)}$ | Input capacitance | $V_I = 3 \text{ V}$ or 0 | | 11 | | pF |
| $C_{io(off)}$ | I/O pin off-state capacitance | $V_O = 3 \text{ V}$ or 0, $V_{EN} = 0$ | | 4.0 | 6.0 | pF |
| $C_{io(on)}$ | I/O Pin on-state capacitance | $V_O = 3 \text{ V}$ or 0, $V_{EN} = 3 \text{ V}$ | | 10.5 | 12.5 | pF |
| $r_{on}^{(2)}$ | On-state resistance | $V_I = 0, I_O = 64 \text{ mA}$ | $V_{ref_A} = 3.3 \text{ V}; V_{ref_B} = V_{EN} = 5 \text{ V}$ | 8.0 | | Ω |
| | | | $V_{ref_A} = 1.8 \text{ V}; V_{ref_B} = V_{EN} = 5 \text{ V}$ | 9.0 | | |
| | | | $V_{ref_A} = 1.0 \text{ V}; V_{ref_B} = V_{EN} = 5 \text{ V}$ | 10 | | |
| | | $V_I = 0, I_O = 32 \text{ mA}$ | $V_{ref_A} = 1.8 \text{ V}; V_{ref_B} = V_{EN} = 5 \text{ V}$ | 10 | | Ω |
| | | | $V_{ref_A} = 2.5 \text{ V}; V_{ref_B} = V_{EN} = 5 \text{ V}$ | 15 | | |
| | | $V_I = 1.8 \text{ V}, I_O = 15 \text{ mA}$ | $V_{ref_A} = 3.3 \text{ V}; V_{ref_B} = V_{EN} = 5 \text{ V}$ | 9.0 | | Ω |
| | | $V_I = 1.0 \text{ V}, I_O = 10 \text{ mA}$ | $V_{ref_A} = 1.8 \text{ V}; V_{ref_B} = V_{EN} = 3.3 \text{ V}$ | 18 | | Ω |
| | | $V_I = 0 \text{ V}, I_O = 10 \text{ mA}$ | $V_{ref_A} = 1.0 \text{ V}; V_{ref_B} = V_{EN} = 3.3 \text{ V}$ | 20 | | Ω |
| $V_I = 0 \text{ V}, I_O = 10 \text{ mA}$ | $V_{ref_A} = 1.0 \text{ V}; V_{ref_B} = V_{EN} = 1.8 \text{ V}$ | 30 | | Ω | | |

(1) All typical values are at $T_A = 25^\circ\text{C}$.

(2) Measured by the voltage drop between the A and B pins at the indicated current through the switch. On-state resistance is determined by the lowest voltage of the two (A or B) pins.

6.6 Switching Characteristics (Translating Down): $V_{GATE} = 3.3\text{ V}$

over recommended operating free-air temperature range, $V_{GATE} = 3.3\text{ V}$, $V_{IH} = 3.3\text{ V}$, $V_{IL} = 0$, and $V_M = 1.15\text{ V}$ (unless otherwise noted) (see [Parameter Measurement Information](#) table)

| PARAMETER | TEST CONDITIONS | $C_L = 50\text{ pF}$ | | | $C_L = 30\text{ pF}$ | | | $C_L = 15\text{ pF}$ | | | UNIT |
|-----------|--|----------------------|-----|-----|----------------------|-----|-----|----------------------|-----|-----|------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| t_{PLH} | Propagation delay time, low-to-high output From (input) A or B to (output) B or A | | 1.1 | | | 0.7 | | | 0.3 | | ns |
| t_{PHL} | Propagation delay time, high-to-low output From (input) A or B to (output) B or A | | 1.2 | | | 0.8 | | | 0.4 | | |

6.7 Switching Characteristics (Translating Down): $V_{GATE} = 2.5\text{ V}$

over recommended operating free-air temperature range, $V_{GATE} = 2.5\text{ V}$, $V_{IH} = 2.5\text{ V}$, $V_{IL} = 0$, and $V_M = 0.75\text{ V}$ (unless otherwise noted) (see [Parameter Measurement Information](#) table)

| PARAMETER | TEST CONDITIONS | $C_L = 50\text{ pF}$ | | | $C_L = 30\text{ pF}$ | | | $C_L = 15\text{ pF}$ | | | UNIT |
|-----------|--|----------------------|-----|-----|----------------------|-----|-----|----------------------|------|-----|------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| t_{PLH} | Propagation delay time, low-to-high output From (input) A or B to (output) B or A | | 1.2 | | | 0.8 | | | 0.35 | | ns |
| t_{PHL} | Propagation delay time, high-to-low output From (input) A or B to (output) B or A | | 1.3 | | | 1 | | | 0.5 | | |

6.8 Switching Characteristics Translating Up): $V_{GATE} = 3.3\text{ V}$

over recommended operating free-air temperature range, $V_{GATE} = 3.3\text{ V}$, $V_{IH} = 2.3\text{ V}$, $V_{IL} = 0$, $V_T = 3.3\text{ V}$, $V_M = 1.15\text{ V}$ and $R_L = 300$ (unless otherwise noted) (see [Parameter Measurement Information](#) table)

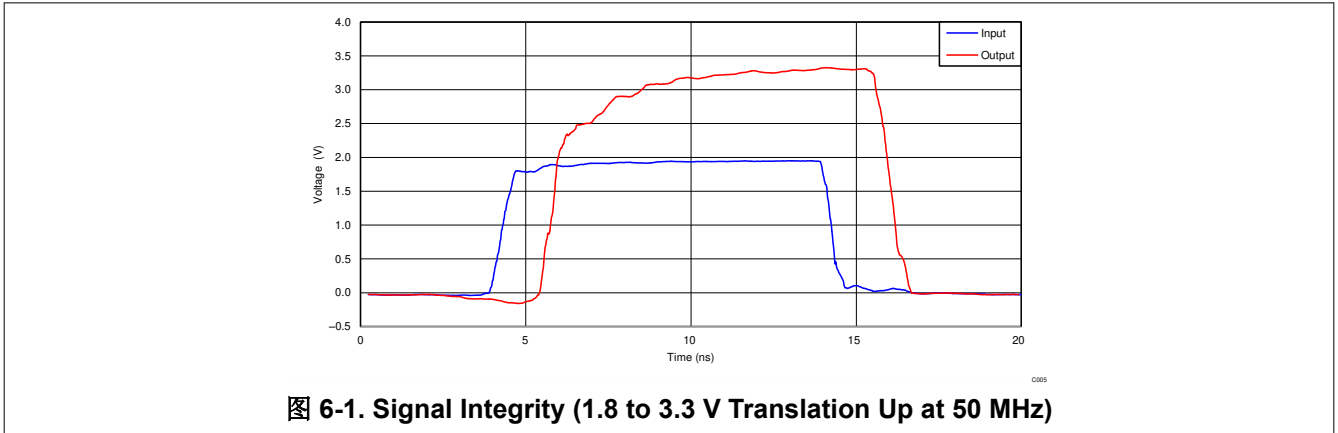
| PARAMETER | TEST CONDITIONS | $C_L = 50\text{ pF}$ | | | $C_L = 30\text{ pF}$ | | | $C_L = 15\text{ pF}$ | | | UNIT |
|-----------|--|----------------------|-----|-----|----------------------|-----|-----|----------------------|-----|-----|------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| t_{PLH} | Propagation delay time, low-to-high output From (input) A or B to (output) B or A | | 1 | | | 0.8 | | | 0.4 | | ns |
| t_{PHL} | Propagation delay time, high-to-low output From (input) A or B to (output) B or A | | 1 | | | 0.9 | | | 0.4 | | |

6.9 Switching Characteristics (Translating Up): $V_{GATE} = 2.5\text{ V}$

over recommended operating free-air temperature range, $V_{GATE} = 2.5\text{ V}$, $V_{IH} = 1.5\text{ V}$, $V_{IL} = 0$, $V_T = 2.5\text{ V}$, $V_M = 0.75\text{ V}$ and $R_L = 300$ (unless otherwise noted) (see [Parameter Measurement Information](#) table)

| PARAMETER | TEST CONDITIONS | $C_L = 50\text{ pF}$ | | | $C_L = 30\text{ pF}$ | | | $C_L = 15\text{ pF}$ | | | UNIT |
|-----------|--|----------------------|-----|-----|----------------------|-----|-----|----------------------|------|-----|------|
| | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| t_{PLH} | Propagation delay time, low-to-high output From (input) A or B to (output) B or A | | 1.1 | | | 0.9 | | | 0.45 | | ns |
| t_{PHL} | Propagation delay time, high-to-low output From (input) A or B to (output) B or A | | 1.3 | | | 1.1 | | | 0.6 | | |

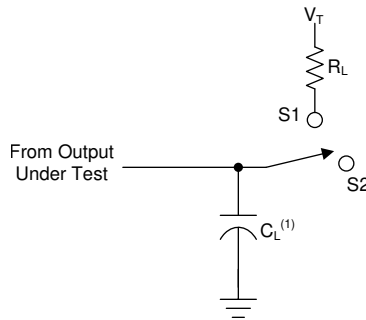
6.10 Typical Characteristics



Parameter Measurement Information

The outputs are measured one at a time, with one transition per measurement. All input pulses are supplied by generators that have the following characteristics:

- $PRR \leq 10 \text{ MHz}$
- $Z_O = 50 \ \Omega$
- $t_r \leq 2 \text{ ns}$
- $t_f \leq 2 \text{ ns}$



A. C_L includes probe and jig capacitance.

图 7-1. Load Circuit

| USAGE | SWITCH |
|------------------------------------|----------|
| Translating Up Translating Down | S1 S2 |

图 7-2. Translating Up and Down Table

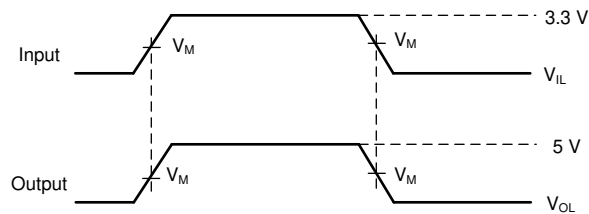


图 7-3. Translating Up

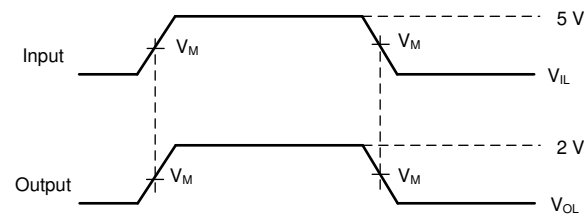


图 7-4. Translating Down

7 Detailed Description

7.1 Overview

The LSF0102-Q1 device can be used in level translation applications for interfacing devices or systems operating at different interface voltages. The LSF0102-Q1 device is ideal for use in applications where an open-drain driver is connected to the data I/Os. With appropriate pull-up resistors and layout, the LSF0102-Q1 device can achieve 100 MHz. The LSF0102-Q1 can also be used in applications where a push-pull driver is connected to the data I/Os.

7.2 Functional Block Diagrams

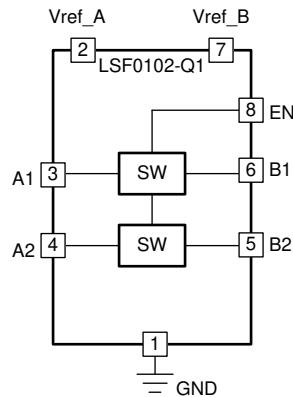


图 7-1. LSF0102-Q1 Functional Block Diagram

7.3 Feature Description

7.3.1 Auto Bidirectional Voltage Translation

The LSF0102-Q1 device is an auto bidirectional voltage level translator that operates from 0.95 to 4.5 V on Vref_A and 1.8 to 5.5 V on Vref_B. This allows bidirectional voltage translation between 0.95 V and 5.5 V without the need for a direction pin in open-drain or push-pull applications. The LSF0102-Q1 device supports level translation applications with transmission speeds greater than 100 Mbps for open-drain systems using a 250-Ω pullup resistor with a 30-pF capacitive load.

7.3.2 Output Enable

When EN is HIGH, the translator switch is on, and the An I/O is connected to the Bn I/O, respectively, allowing bidirectional data flow between ports. When EN is LOW, the translator switch is off, and a high-impedance state exists between ports. To enable the I/O pins, the EN input should be tied directly to Vref_B. To ensure the high-impedance state during power-up or power-down, EN must be LOW. For additional details on how to use the enable pin, see the [Using the Enable Pin with the LSF Family](#) video.

表 7-1. Enable Function Table

| INPUT EN ⁽¹⁾ PIN | FUNCTION |
|-----------------------------|----------|
| Tied directly to Vref_B | An = Bn |
| L | Hi-Z |

(1) EN is controlled by Vref_B logic levels and should be at least 1 V higher than Vref_A for best translator.

7.3.3 Mixed-Mode Voltage Translation

The supply voltage (Vpu#) for each channel can be individually set up with a pull-up resistor. For example, CH1 can be used in up-translation mode (1.2 V ↔ 3.3 V) and CH2 in down-translation mode (2.5 V ↔ 1.8 V). For additional details on how to use the LSF0102-Q1 for mixed-mode voltage translation, see the [Multi-Voltage Translation with the LSF Family](#) video.

7.4 Device Functional Modes

When the An or Bn port is LOW, the switch is in the ON-state and a low resistance connection exists between the An and Bn ports. The low R_{on} of the switch allows connections to be made with minimal propagation delay and signal distortion. Assuming the higher voltage is on the Bn port when the Bn port is HIGH, the voltage on the An port is limited to the voltage set by Vref_A. When the An port is HIGH, the Bn port is pulled to the drain pull-up supply voltage ($V_{pu\#}$) by the pull-up resistors. This functionality allows a seamless translation between higher and lower voltages selected by the user without the need for direction control. For additional details on the functional operation of the LSF0102-Q1, see the [Down Translation with the LSF Family](#) and [Up Translation with the LSF Family](#) videos.

8 Application and Implementation

Note

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

The LSF0102-Q1 device is able to perform voltage translation for open-drain or push-pull interfaces such as I²C, SPI, UART, MDIO, SDIO, and GPIO.

8.2 Typical Application

8.2.1 Bidirectional Translation

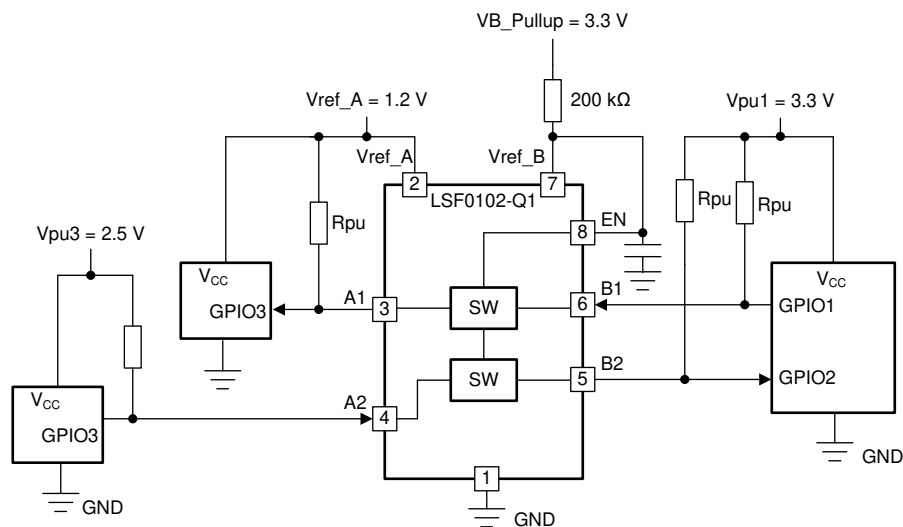


图 8-1. Bidirectional Translation to Multiple Voltage Levels

8.2.1.1 Design Requirements

8.2.1.1.1 Enable, Disable, and Reference Voltage Guidelines

The LSF0102-Q1 device has an EN input that is used to disable the device by setting EN LOW, which places all I/Os in the high-impedance state. Since LSF family is switch-type voltage translator, the power consumption is very low. It is recommended to always enable LSF0102-Q1 device for bidirectional applications by connecting the EN pin to the Vref_B pin, as shown in 图 8-1. For additional details on setting up the Vref_A, Vref_B, and EN pins, see the [Understanding the Bias Circuit for the LSF Family](#) video.

表 8-1. Application Operating Condition

| PARAMETER | MIN | TYP | MAX | UNIT |
|---|------|-----|-----|------|
| Vref_A ⁽¹⁾ reference voltage (A) | 0.95 | | 4.5 | V |

表 8-1. Application Operating Condition (continued)

| PARAMETER | | MIN | TYP | MAX | UNIT |
|--------------------|-------------------------|--------------|--------|--------|------|
| Vref_B | reference voltage (B) | Vref_A + 0.8 | | 5.5 | V |
| V _{I(EN)} | input voltage on EN pin | Vref_A + 0.8 | Vref_B | 5.5 | V |
| V _{pu} | pull-up supply voltage | 0 | | Vref_B | V |

(1) Vref_A is required to be the lowest voltage level across all inputs and outputs.

The 200 kΩ, pull-up resistor is required to allow Vref_B to regulate the EN input. A filter capacitor on Vref_B is recommended. Also Vref_B and V_{I(EN)} are recommended to be 1.0 V higher than Vref_A for best signal integrity.

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Bidirectional Translation

For the bidirectional clamping configuration (higher voltage to lower voltage or lower voltage to higher voltage), the EN input must be connected to Vref_B and both pins pulled to HIGH side V_{pu} through a pull-up resistor (typically 200 kΩ), as shown in 图 8-1. This allows Vref_B to regulate the EN input. A filter capacitor on Vref_B is recommended. The controller output driver can be push-pull or open-drain (pull-up resistors may be required) and the peripheral device output can be push-pull or open-drain (pull-up resistors are required to pull the Bn outputs to V_{pu}).

If either output is push-pull, data must be unidirectional or the outputs must be tri-state and be controlled by some direction-control mechanism to prevent HIGH-to-LOW contention in either direction. If both outputs are open-drain, no direction control is needed.

In 图 8-1, the reference supply voltage (Vref_A) is connected to the processor core power supply voltage. When Vref_B is connected through a 200 kΩ resistor to a 3.3 V V_{pu} power supply, and Vref_A is set 1.2 V. The output of A1 has a maximum output voltage equal to Vref_A, and the bidirectional interface on channel 2 has a maximum output voltage equal to V_{pu}.

8.2.1.2.2 Pull-up Resistor Sizing

To maintain an appropriate output low voltage, the pull-up resistor value should limit the current through the pass transistor when it is in the ON state to less than 15 mA. This ensures a pass voltage of 260 mV to 350 mV. To set the current through each pass transistor at 15 mA, the pull-up resistor value can be calculated using the following equation:

$$R_{pu} = (V_{pu} - 0.35 \text{ V}) / 0.015 \text{ A} \quad (1)$$

The appropriate pull up resistor will depend on the current requirements of the application. 表 8-2 summarizes resistor values, reference voltages, and currents at 15 mA, 10 mA, and 3 mA. The resistor value shown in the +10% column (or a larger value) should be used to ensure that the pass voltage of the transistor is 350 mV or less. The external driver must be able to sink the total current from the resistors on both sides of the LSF0102-Q1 device at 0.175 V, although the 15 mA applies only to current flowing through the LSF0102-Q1.

表 8-2. Pull-up Resistor Values

| V _{DPU} | 15 mA | | 10 mA | | 3 mA | |
|------------------|-------------|-------------------------|-------------|-------------------------|-------------|-------------------------|
| | NOMINAL (Ω) | +10% ⁽¹⁾ (Ω) | NOMINAL (Ω) | +10% ⁽¹⁾ (Ω) | NOMINAL (Ω) | +10% ⁽¹⁾ (Ω) |
| 5 V | 310 | 341 | 465 | 512 | 1550 | 1705 |
| 3.3 V | 197 | 217 | 295 | 325 | 983 | 1082 |
| 2.5 V | 143 | 158 | 215 | 237 | 717 | 788 |
| 1.8 V | 97 | 106 | 145 | 160 | 483 | 532 |
| 1.5 V | 77 | 85 | 115 | 127 | 383 | 422 |
| 1.2 V | 57 | 63 | 85 | 94 | 283 | 312 |

(1) +10% to compensate for V_{DD} range and resistor tolerance

8.2.1.3 Application Curve

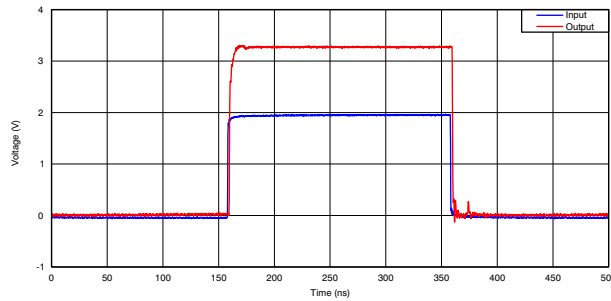


图 8-2. Captured Waveform From Above I²C Set-Up (1.8 V to 3.3 V at 2.5 MHz)

9 Power Supply Recommendations

There are no power sequence requirements for the LSF family. For recommended operating voltages for all supply and input pins, see 表 9-1.

表 9-1. Recommended Operating Voltages

| PARAMETER | | MIN | TYP | MAX | UNIT |
|-----------------------|-------------------------|--------------|-----|--------|------|
| Vref_A ⁽¹⁾ | reference voltage (A) | 0.95 | | 4.5 | V |
| Vref_B | reference voltage (B) | Vref_A + 0.8 | | 5.5 | V |
| V _{I(EN)} | input voltage on EN pin | Vref_A + 0.8 | | 5.5 | V |
| V _{pu} | pull-up supply voltage | 0 | | Vref_B | V |

10 Layout

10.1 Layout Guidelines

Because the LSF0102-Q1 device is a switch-type level translator, the signal integrity is dependent upon the pull-up resistor value and PCB board parasitics. Consider the following recommendations when designing with the LSF0102-Q1.

- Minimize the signal trace length to reduce capacitance
- Avoid using stubs in the signal path to reduce parasitics.
- Place the LSF0102-Q1 device near the high voltage side.
- Select the appropriate pull-up resistor that applies to translation levels and driving capability of transmitter.

10.2 Layout Example

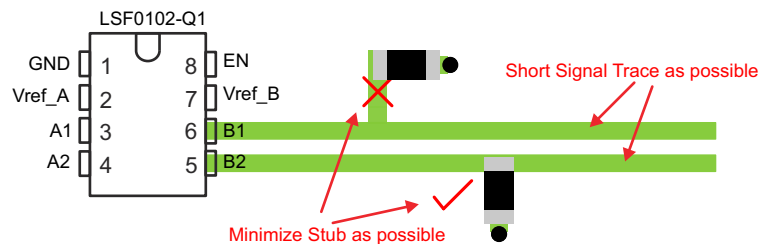


图 10-1. Short Trace Layout

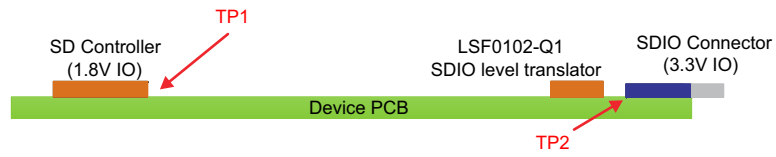


图 10-2. Device Placement

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [TI Logic Minute: Introduction - Voltage Level Translation with the LSF Family](#) video
- Texas Instruments, [Voltage-Level Translation with the LSF Family](#) application report

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11.6 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| LSF0102QDCURQ1 | ACTIVE | VSSOP | DCU | 8 | 3000 | RoHS & Green | NIPDAUAG | Level-2-260C-1 YEAR | -40 to 125 | NG2SQ | Samples |

(1) The marketing status values are defined as follows:

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(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF LSF0102-Q1 :

- Catalog : [LSF0102](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

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